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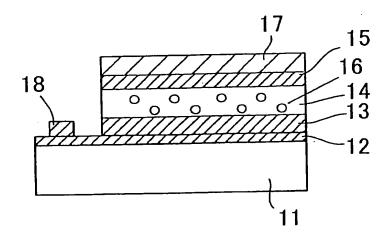
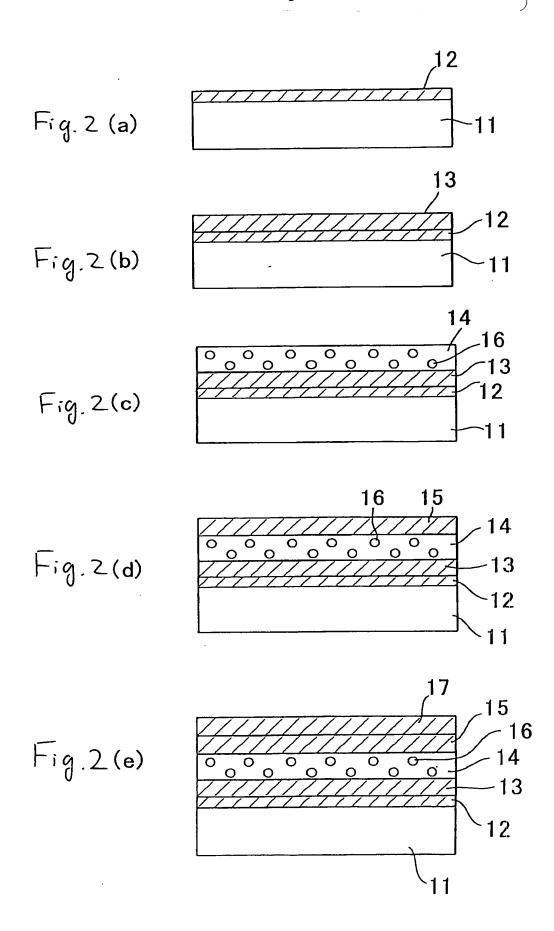


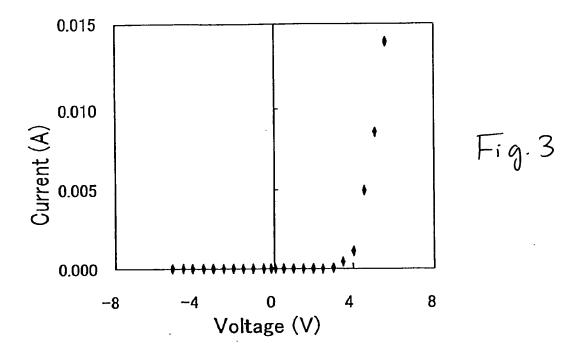
Fig. 1

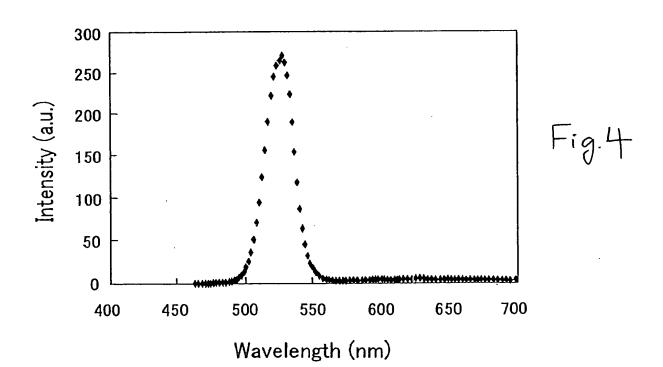
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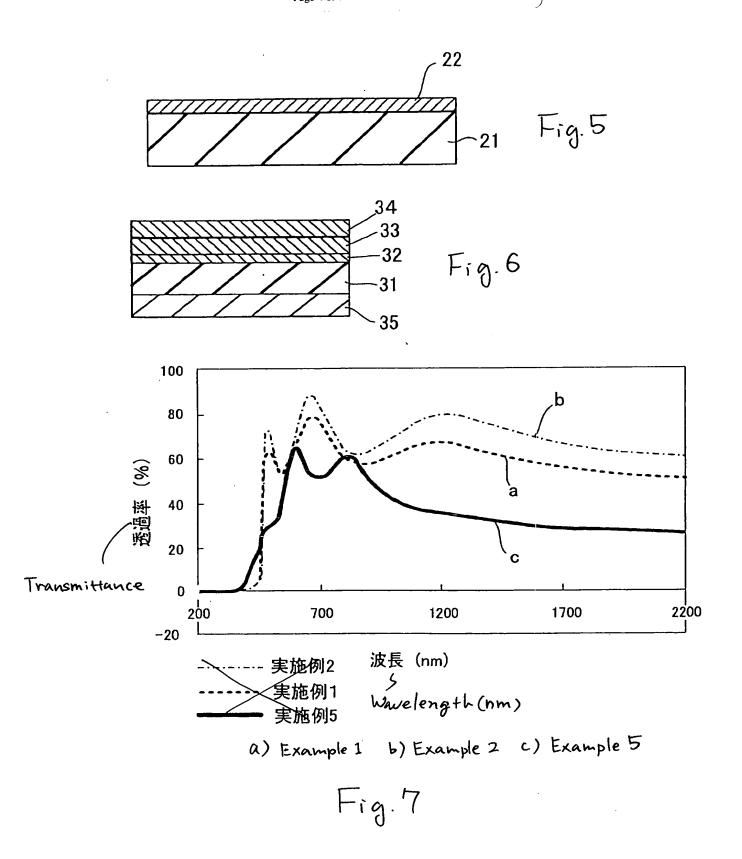
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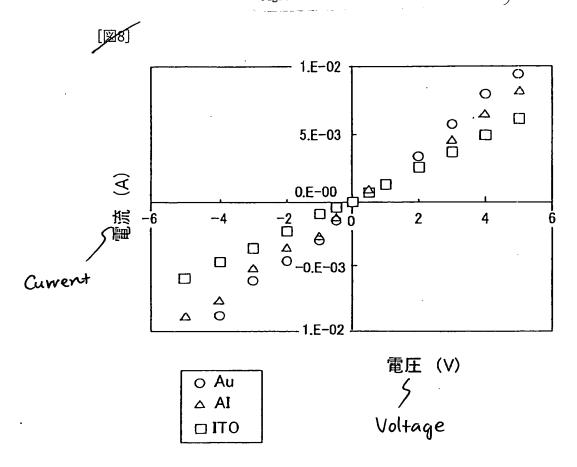


Fig.8

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